

SLD234VL

Index-Guided High Power AlGaAs Laser Diode

Description

The SLD234VL is a high power index-guided AlGaAs laser diode.

Features

- High power
- Low power consumption
- Low astigmatism

Applications

Pickups for optical discs

Structure

- AlGaAs quantum well-structured laser diode
- PIN photodiode for optical power output monitor

Recommended Operating Optical Power Output

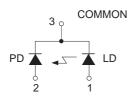
50mW

Absolute Maximum Ratings (Tc = 25°C)

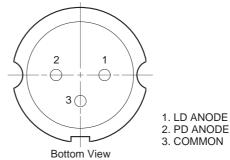
 Optical power output 	Po		50	mW	(CW)
			80	mW	(Pulse)
					Pulse period of $1\mu s$ or less
					Duty of 50% or less
 Reverse voltage 	Vr	LD	2	V	
		PD	15	V	
Operating temperature	Тор	r	-10 to +60	°C	

 Storage temperature Tstg -40 to +85 °C

Connection Diagram

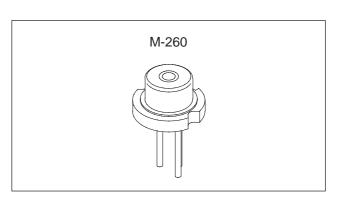


Pin Configuration



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Optical and Electrical Characteristics (Tc = 25°C)

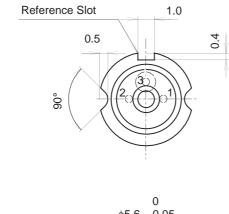
Tc: Case temperature

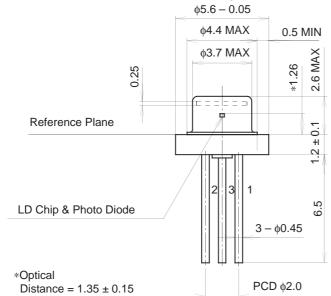
Item		Symbol	Conditions	Min.	Тур.	Max.	Unit
Threshold current		lth	CW	15	20	30	mA
Operating current		Іор	CW, Po = 50mW	60	70	85	mA
Operating voltage		Vop	CW, Po = 50mW	—	2.0	2.5	V
Oscillation wavelength		λρ	CW, Po = 50mW	775	785	795	nm
Differential efficiency		ηD	CW, Po = 50mW	0.8	1.0	1.3	mW/mA
Radiation	Parallel	θ//	CW, Po = 50mW	7	8.5	10	degree
angle	ngle Perpendicular θ⊥		CW, Po = 50mW	19	22	27	degree
Astigmatism		As	CW, Po = 50mW		_	-6	μm
Monitor current		Im	CW, Po = 50mW, VR (PIN) = 5V	_	0.05	_	mA
	Angle	Δφ//	CW, Po = 50mW		_	±2.0	degree
Positional accuracy	Angle	$\Delta \phi \bot$	CW, Po = 50mW	_	_	±3.0	degree
	Position	ΔΧ, ΔΥ, ΔΖ			_	±80	μm

Package Outline Un

Unit: mm

M-260





SONY CODE	M-260		
EIAJ CODE			
JEDEC CODE		PACKAGE WEIGHT	0.3g